

# LED DISPLAY DRIVERS

- M5450 34 OUTPUTS/15mA SINK
- M5451 35 OUTPUTS/15mA SINK
- CURRENT GENERATOR OUTPUTS (NO EXTERNAL RESISTORS REQUIRED)
- CONTINUOUS BRIGHTNESS CONTROL
- SERIAL DATA INPUT
- ENABLE (ON M5450)
- WIDE SUPPLY VOLTAGE OPERATION
- TTL COMPATIBILITY

#### Application examples:

- MICROPROCESSOR DISPLAYS
- INDUSTRIAL CONTROL INDICATOR
- RELAY DRIVER
- INSTRUMENTATION READOUTS

The M5450 and M5451 are monolithic MOS integrated circuits produced with an N-channel

silicon gate technology. They are available in 40-pin dual in-line plastic packages.

A single pin controls the LED display brightness by setting a reference current through a variable resistor connected to  $V_{DD}$  or to a separate supply of 13.2V maximum.

The M5450 and M5451 are pin-to-pin replacements of the NS MM 5450 and MM 5451.



#### ABSOLUTE MAXIMUM RATINGS

VDD	Supply voltage	-0.3 to 15	v
V,	Input voltage	-0.3 to 15	V
V <sub>O (off)</sub>	Off state output voltage	15	v
l <sub>o</sub> `´	Output sink current	40	mA
P <sub>tot</sub>	Total package power dissipation	at 25°C	1W
		at 85°C	560 mW
T <sub>j</sub>	Junction temperature	150	°C
Top	Operating temperature range	-25 to 85	°C
T <sub>stg</sub>	Storage temperature range	-65 to 150	°C
		1	

Stresses above those listed under "Absolute Maximum Ratings" may causes permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## CONNECTION DIAGRAMS

vss (1	40	OUTPUT BIT 18	vss []	40	OUTPUT BIT 18
OUTPUT BIT 17 [ 2	39	OUTPUT BIT 19	OUTPUT BIT 17 2	39	OUTPUT BIT 19
OUTPUT BIT 16 ( 3	38	OUTPUT BIT 20	OUTPUT BIT 16 3	38	OUTPUT BIT 20
OUTPUT BIT 15 [ 4	37	OUTPUT BIT 21	OUTPUT BIT 15 4	37	OUTPUT BIT 21
OUTPUT BIT 14 5	36	OUTPUT BIT 22	OUTPUT BIT 14 5	36	OUTPUT BIT 22
OUTPUT BIT 130 6	35	OUTPUT BIT 23	OUTPUT BIT 130 6	35	OUTPUT BIT 23
OUTPUT BIT 12 1 7	34	OUTPUT BIT 24	OUTPUT B(T 12 7	34	OUTPUT BIT 24
	33	OUTPUT BIT 25	OUTPUT BIT 11 0 8	33	OUTPUT BIT 25
OUTPUT BIT 10 1 9	32	OUTPUT BIT 26		32	OUTPUT BIT 26
OUTPUT BIT 9 10	M5450 31	OUTPUT BIT 27	OUTPUT BIT 9 10	M5451 31	OUTPUT BIT 27
OUTPUT BIT 8 11	30	OUTPUT BIT 28	OUTPUT BIT 8 [11	30	OUTPUT BIT 28
OUTPUT BIT 7 12	29	OUTPUT BIT 29	OUTPUT BIT 7 12	29	OUTPUT BIT 29
OUTPUT BIT 6 13	28	OUTPUT BIT 30	OUTPUT BIT 6 13	28	OUTPUT BIT 30
OUTPUT BIT S 14	27	JOUTPUT BIT 31	OUTPUT BIT 5 [14	27	OUTPUT BIT 31
OUTPUT BIT 4 [15	26	OUTPUT BIT 32	OUTPUT BIT 4 15	26	OUTPUT BIT 32
OUTPUT BIT 3 [16	25	OUTPUT BIT 33	OUTPUT BIT 3 16	25	OUTPUT BIT 33
OUTPUT BIT 2 17	24	OUTPUT BIT 34	OUTPUT BIT 2 17	24	OUTPUT BIT 34
OUTPUT BIT 1 [18	23	DATA ENABLE	OUTPUT BIT 1 [18	23	OUTPUT BIT 35
BRIGHTNESS [19 CONTROL	22	DATA IN	BRIGHTNESS [19	22	DATA IN
YOD [20	21	CLOCK IN	YDD C 20	21	CLOCK IN
	5-5795			5-5796	

OUTPUT BIT34 OUTPUT BIT1 VDD BRIGHTNESS 20 24 18 100KQ 19 35 OUTPUT BUFFERS 1nF LOAD 35 LATCHES DATA ENABLE (M5450) OUTPUT 35 (M5451) 23 SERIAL 22 35 BIT SHIFT REGISTER DATA -CLOCK RESET 21 1 S-5797

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BLOCK DIAGRAM Fig. 1 **STATIC ELECTRICAL CHARACTERISTICS** ( $T_{amb}$  within operating range,  $V_{DD}$  = 4.75V to 13.2V,  $V_{SS}$  = 0V, unless otherwise specified)

Parameter		Test conditions	Min.	Typ.	Max.	Unit
V <sub>DD</sub>	Supply Voltage		4.75		13.2	v
DD	Supply Current	V <sub>DD</sub> = 13.2V			7	mA
Vı	Input Voltage Logical ''0'' Level Logical ''1'' Level	$\pm$ 10 μA input bias 4.75 $\leq V_{DD} \leq 5.25$ $V_{DD} > 5.25$	-0.3 2.2 V <sub>DD</sub> -2		0.8 V <sub>DD</sub> V <sub>DD</sub>	v v v
I <sub>B</sub>	Brightness Input Current (note 2)		0		0.75	mA
VB	Brightness Input Voltage (pin 19)	Input current = 750 μA	3		4.3	v
V <sub>O (off)</sub>	Off State Out. Voltage				13.2	V
Io	Out. Sink Current (note 3) Segment OFF Segment ON	$V_O = 3V$ $V_O = 1V$ (note 4) Brightness In. = 0 $\mu$ A Brightness In. = 100 $\mu$ A Brightness In. = 750 $\mu$ A	0 2	2.7	10 10 4	μΑ μΑ mA
		Brightness III. = 750 µA	12	15	25	mA
fclock	Input Clock Frequency		0		0.5	MHz
I <sub>O</sub>	Output Matching (note 1)				± 20	%

Notes: 1. Output matching is calculated as the percent variation from  $I_{MAX} + I_{MIN}/2$ .

2. With a fixed resistor on the brightness input some variation in brightness will occur from one device to another.

- 3. Absolute maximum for each output should be limited to 40 mA.
- 4. The V<sub>O</sub> voltage should be regulated by the user. See figures 5 and 6 for allowable V<sub>O</sub> versus I<sub>O</sub> operation.

### FUNCTIONAL DESCRIPTION

Both the M5450 and the M5451 are specifically designed to operate 4 or 5-digit alphanumeric displays with minimal interface with the display and the data source. Serial data transfer from the data source to the display driver is accomplished with 2 signals, serial data and clock. Using a format of a leading "1" followed by the 35 data bits allows data transfer without an additional load signal. The 35 data bits are latched after the 36th bit is complete, thus providing non-multiplexed, direct drive to the display. Outputs change only if the serial data bits differ from the previous time.

Display brightness is determined by control of the output current LED displays.

A 1nF capacitor should be connected to brightness control, pin 19, to prevent possible oscillations. A block diagram is shown in figure 1. For the M5450 a DATA ENABLE is used instead of the 35th output. The DATA ENABLE input is a metal option for the M5450.



## FUNCTIONAL DESCRIPTION (continued)

The output current is typically 20 times greater than the current into pin 19, which is set by an external variable resistor. There is an internal limiting resistor of  $400\Omega$  nominal value.

Figure 2 shows the input data format. A start bit of logical "1" precedes the 35 bits of data. At the 36th clock a LOAD signal is generated synchronously with the high state of the clock, which loads the 35 bits of the shift registers into the latches.

At the low state of the clock a RESET signal is generated which clears all the shift registers for the next set of data. The shift registers are static master-slave configurations. There is no clear for the master portion of the first shift register, thus allowing continuous operation.

There must be a complete set of 36 clocks or the shift registers will not clear.

When power is first applied to the chip an internal power ON reset signal is generated which resets all registers and all latches. The START bit and the first clock return the chip to its normal operation.

Bit 1 is the first bit following the start bit and it will appear on pin 18. A logical "1" at the input will turn on the appropriate LED.

Figure 3 shows the timing relationship between Data, Clock and DATA ENABLE.

A max clock frequency of 0.5 MHz is assumed.

For applications where a lesser number of outputs are used, it is possible to either increase the current per output or operate the part at higher than  $1V V_{OUT}$ . The following equation can be used for calculations.

 $T_i = [(V_{OUT}) (I_{1ED}) (No. of segments) + (V_{DD} \cdot 7 mA)] (124 °C/W) + T_{amb}$ 

where:

 $T_j = junction temperature (150°C max)$   $V_{OUT} = the voltage at the LED driver outputs$   $I_{LED} = the LED current$  124°C/W = thermal coefficient of the package $T_{amb} = ambient temperature$ 

The above equation was used to plot figure 4, 5 and 6.



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Fig. 2 - Input Data Format

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## TYPICAL APPLICATIONS

Basic electronically tuned Radio or TV system



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## TYPICAL APPLICATIONS (continued)



# POWER DISSIPATION OF THE IC

The power dissipation of the IC can be limited using different configurations.

a)





In this application R must be chosen taking into account the worst operating conditions. R is determined by the maximum number of segments activated

$$R = \frac{V_{C} - V_{D MAX} - V_{O MIN}}{N_{MAX} \cdot I_{D}}$$

The worst case condition for the device is when roughly half of the maximum number of segments are activated.

It must be checked that the total power dissipation does not exceed the absolute maximum ratings of the device.

In critical cases more resistors can be used in conjunction with groups of segments.

In this case the current variation in the single resistor is reduced and  $\mathbf{P}_{tot}$  limited.





In this configuration the drop on the serial connected diodes is quite stable if the diodes are properly chosen.

The total power dissipation of the IC depends, in a first approximation, only on the number of segments activated.

c)



In this configuration  $V_{OUT} + V_D$  is constant. The total power dissipation of the IC depends only on the number of segments activated.

